TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX541F,TC74LCX541FT,TC74LCX541FK

Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX541 is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

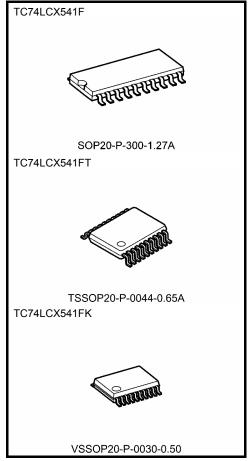
The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

The TC74LCX541 is a non-inverting 3-state buffer having two active-low output enables. When either $\overline{OE}1$ or $\overline{OE}2$ are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

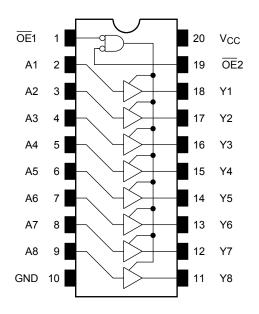
- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 541 type



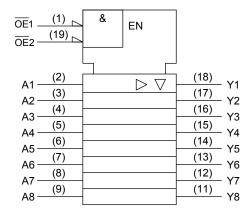
Weight:

SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

| | Inputs | | | | | |
|-----|--------|----------------|---|--|--|--|
| OE1 | OE2 | DE2 An Outputs | | | | |
| Н | Х | Х | Z | | | |
| Х | Н | Х | Z | | | |
| L | L | Н | Н | | | |
| L | L | L | L | | | |

X: Don't care

Z: High impedance



Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|-----------------------------------|-------------------------------|------|
| Power supply voltage | V _{CC} | -0.5 to 7.0 | |
| DC input voltage | V _{IN} | -0.5 to 7.0 | V |
| | | -0.5 to 7.0 (Note 2) | |
| DC output voltage | V _{OUT} | -0.5 to V _{CC} + 0.5 | V |
| | | (Note 3) | |
| Input diode current | l _{IK} | -50 | mA |
| Output diode current | lok | ±50 (Note 4) | mA |
| DC output current | lout | ±50 | mA |
| Power dissipation | P_{D} | 180 | mW |
| DC V _{CC} /ground current | I _{CC} /I _{GND} | ±100 | mA |
| Storage temperature | T _{stg} | –65 to 150 ° | |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

| Characteristics | Symbol | ol Rating | | | |
|--------------------------|----------------------------------|-------------------------------|------|--|--|
| Power supply voltage | V _{CC} | 2.0 to 3.6 | | | |
| rower suppry voltage | vCC | 1.5 to 3.6 (Note 2) | V | | |
| Input voltage | V _{IN} | 0 to 5.5 | ٧ | | |
| Output voltage | V | 0 to 5.5 (Note 3) | V | | |
| Output voltage | V _{OUT} | 0 to V _{CC} (Note 4) | V | | |
| Output current | la/la. | ±24 (Note 5) | mA | | |
| Output current | I _{OH} /I _{OL} | ±12 (Note 6) | IIIA | | |
| Operating temperature | T _{opr} | -40 to 85 | °C | | |
| Input rise and fall time | dt/dv | 0 to 10 (Note 7) | ns/V | | |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

| Characteristics | | Cumbal | Symbol Test Condition | | | Min | May | Unit | | |
|-----------------------------------|-------------|------------------|---|--------------------------------------|--|-------------------------|-------|------|-----|--|
| Character | Sucs | Symbol | rest Condition | | V _{CC} (V) | IVIIII | Max | Unit | | |
| Input voltage | H-level | V _{IH} | | _ | 2.7 to 3.6 | 2.0 | _ | V | | |
| input voltage | L-level | V _{IL} | | _ | 2.7 to 3.6 | _ | 8.0 | v | | |
| | | | | $I_{OH} = -100 \mu A$ | 2.7 to 3.6 | to 3.6 VCC — | | | | |
| | H-level | V _{OH} | V _{IN} = V _{IH} or V _{IL} | $I_{OH} = -12 \text{ mA}$ | 2.7 | 2.2 | _ | | | |
| | | | | $I_{OH} = -18 \text{ mA}$ | 3.0 | 2.4 | _ | | | |
| Output voltage | | | | I _{OH} = -24 mA | 3.0 | 2.2 | _ | V | | |
| | | | V VV | I _{OL} = 100 μA | 2.7 to 3.6 | _ | 0.2 | | | |
| | | V | | I _{OL} = 12 mA | 2.7 | _ | 0.4 | | | |
| | L-level | V _{OL} | VOL VII | $V_{IN} = V_{IH} \text{ or } V_{IL}$ | AIM — AIH OI AIL | I _{OL} = 16 mA | 3.0 | _ | 0.4 | |
| | | | | I _{OL} = 24 mA | 3.0 | _ | 0.55 | | | |
| Input leakage currer | t | I _{IN} | V _{IN} = 0 to 5.5 V | • | 2.7 to 3.6 | _ | ±5.0 | μА | | |
| 3-state output off-sta | ite current | loz | $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OLIT} = 0 \text{ to } 5.5 \text{ V}$ | | 2.7 to 3.6 | _ | ±5.0 | μА | | |
| Power off leakage co | urrent | l _{OFF} | V _{IN} /V _{OUT} = 5.5 V | | 0 | _ | 10.0 | μА | | |
| | | | . V _{IN} = V _{CC} or GND | | V _{IN} = V _{CC} or GND | | _ | 10.0 | | |
| Quiescent supply cu | rrent | ICC | V _{IN} /V _{OUT} = 3.6 to 5.5 V | | 2.7 to 3.6 | _ | ±10.0 | μА | | |
| Increase in I _{CC} per i | nput | Δlcc | $V_{IH} = V_{CC} - 0.6 V$ | | 2.7 to 3.6 | _ | 500 | | | |

AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Min | Max | Unit |
|-------------------------|-------------------|--------------------|---------------------|-----|-----|------|
| Decree with a delection | t _{pLH} | Figure 4 Figure 0 | 2.7 | _ | 7.5 | |
| Propagation delay time | t _{pHL} | Figure 1, Figure 2 | 3.3 ± 0.3 | 1.5 | 6.5 | ns |
| Cutaut analys time | t _{pZL} | Figure 1, Figure 3 | 2.7 | _ | 9.5 | ns |
| Output enable time | t _{pZH} | Figure 1, Figure 3 | 3.3 ± 0.3 | 1.5 | 8.5 | |
| Output disable time | t _{pLZ} | Figure 1, Figure 3 | 2.7 | | 8.5 | ns |
| Output disable time | t _{pHZ} | rigure 1, rigure 3 | 3.3 ± 0.3 | 1.5 | 7.5 | 110 |
| Output to output skew | t _{osLH} | (Note) | 2.7 | 1 | 1 | ns |
| Carpar to output snew | t _{osHL} | (Note) | 3.3 ± 0.3 | | 1.0 | 110 |

Note: Parameter guaranteed by design.

 $(t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \, t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

| Characteristics | | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|------------------------------|-----------------|------------------|--|---------------------|------|------|
| Quiet output maximum dynamic | V _{OL} | V _{OLP} | V _{IH} = 3.3 V, V _{IL} = 0 V | 3.3 | 0.8 | V |
| Quiet output minimum dynamic | V _{OL} | V _{OLV} | V _{IH} = 3.3 V, V _{IL} = 0 V | 3.3 | 0.8 | V |



Capacitive Characteristics (Ta = 25°C)

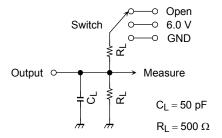
| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|-------------------------------|------------------|--------------------------------|---------------------|------|------|
| Input capacitance | C _{IN} | _ | 3.3 | 7 | pF |
| Output capacitance | C _{OUT} | _ | 3.3 | 8 | pF |
| Power dissipation capacitance | C _{PD} | f _{IN} = 10 MHz (Note |) 3.3 | 40 | pF |

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

AC Test Circuit



| Parameter | Switch |
|-------------------------------------|--------|
| t _{pLH} , t _{pHL} | Open |
| t _{pLZ} , t _{pZL} | 6.0 V |
| t _{pHZ} , t _{pZH} | GND |

Figure 1

AC Waveform

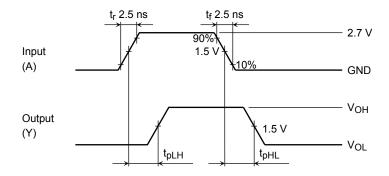


Figure 2 t_{pLH}, t_{pHL}

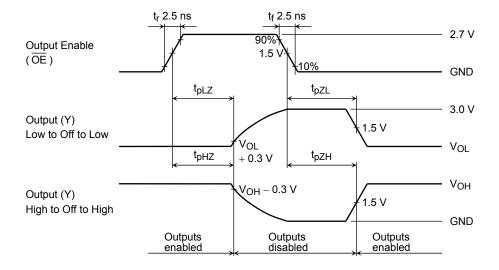
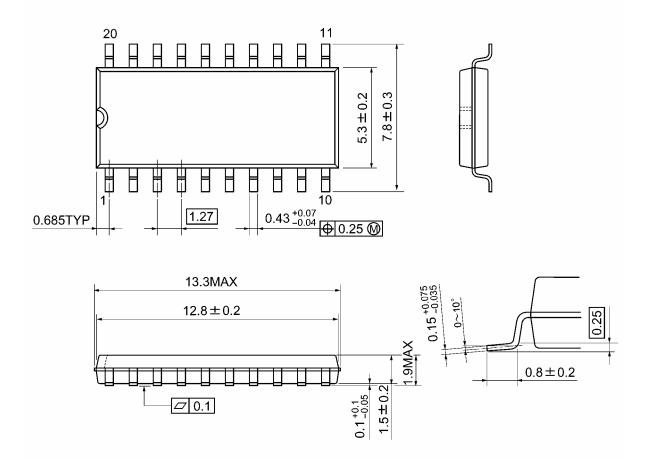


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

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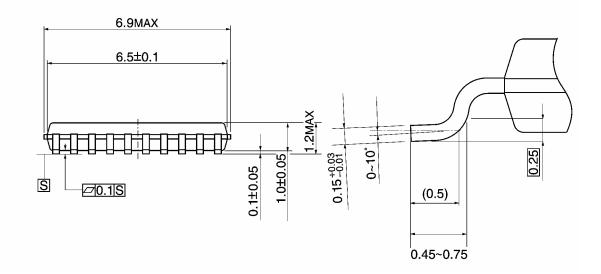
Package Dimensions

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

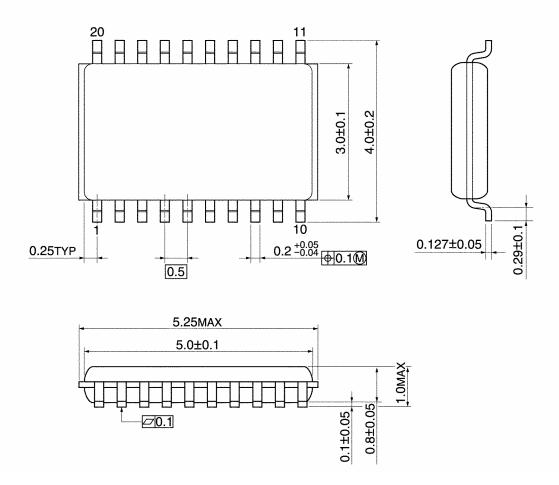
Package Dimensions



Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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